



High Efficient Power Conversion from Car Batteries to Next Generation Microcontroller Systems (PwrSwipe)

Gerhard Maderbacher¹, Karlheinz Kogler¹, Joachim Pichler¹, Federico Capponi¹, Herbert Gruber¹, Sylvia Michaelis¹, Dietrich Michaelis¹,

Andreas Einwanger², Christoph Sandner¹, Anamaria Anca¹, Gottfried Beer²

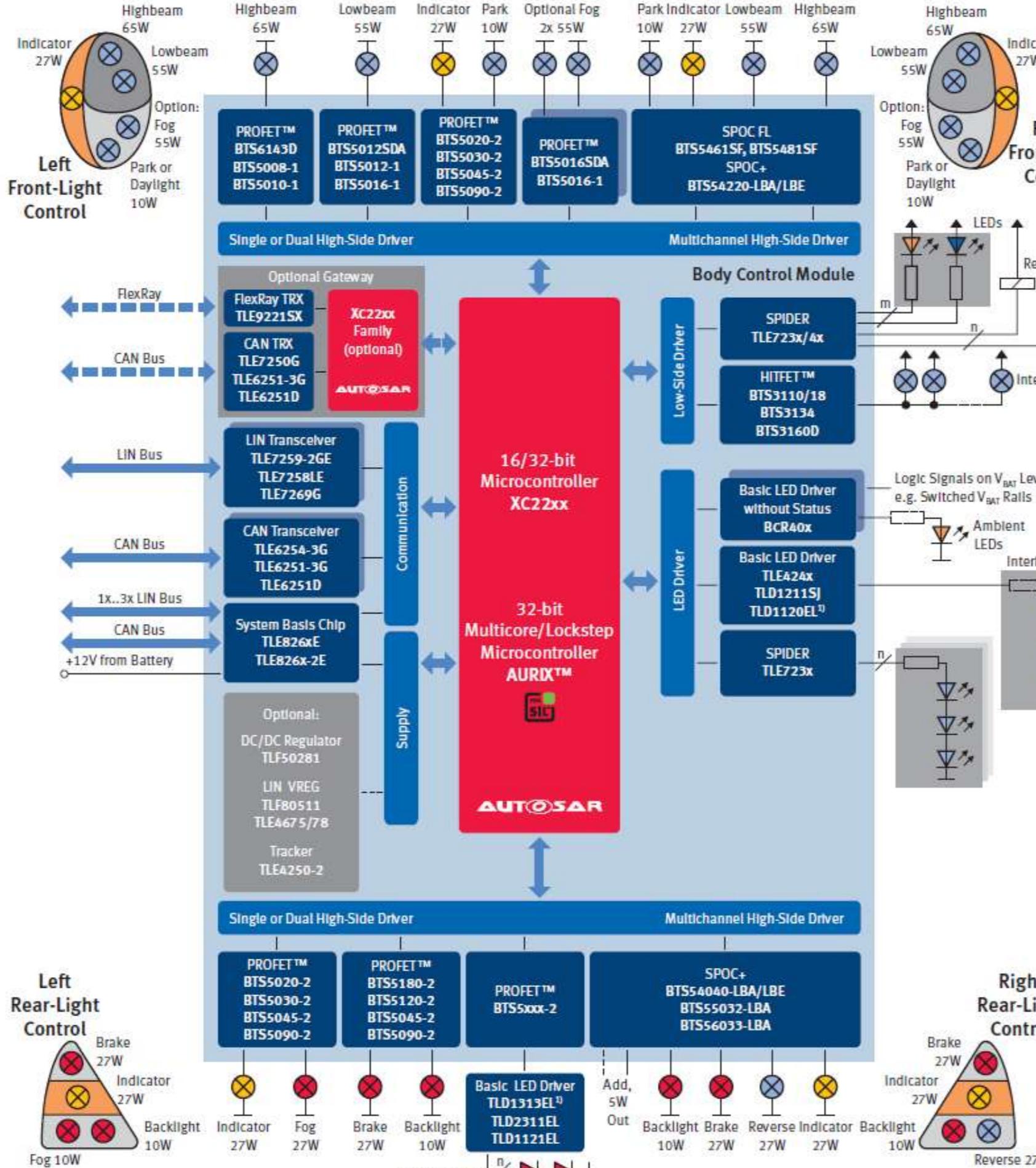
¹Infineon Technologies Austria AG - Villach, ²Infineon Technologies AG - Regensburg



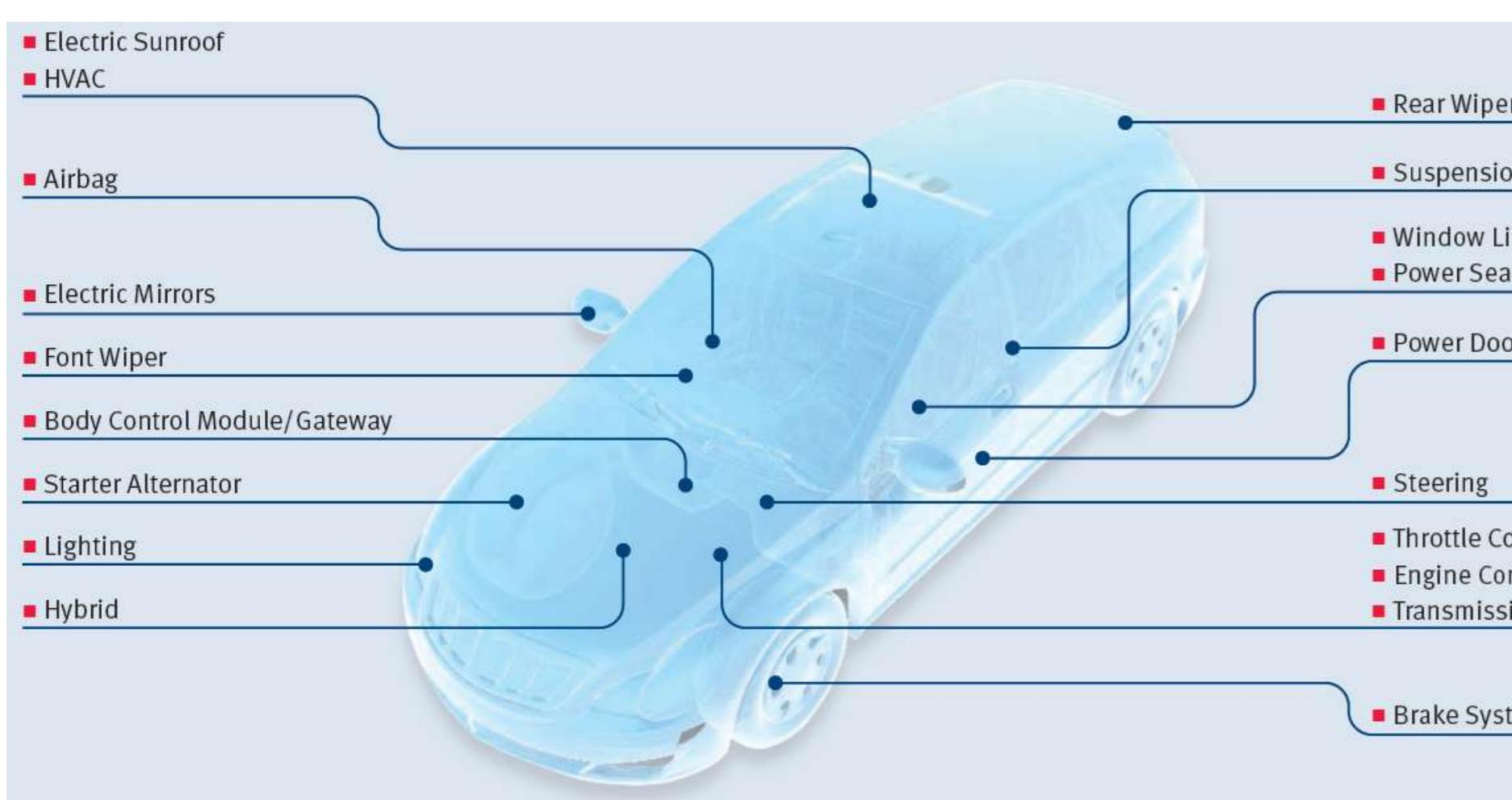
Abstract

- Goal was to design a PMU with reduced footprint at competitive costs and performance
- The target application is an automotive microcontroller system in 40nm CMOS technology with multiple power domains
- This work is a pre-study for next generation fully integrated power management systems for automotive applications

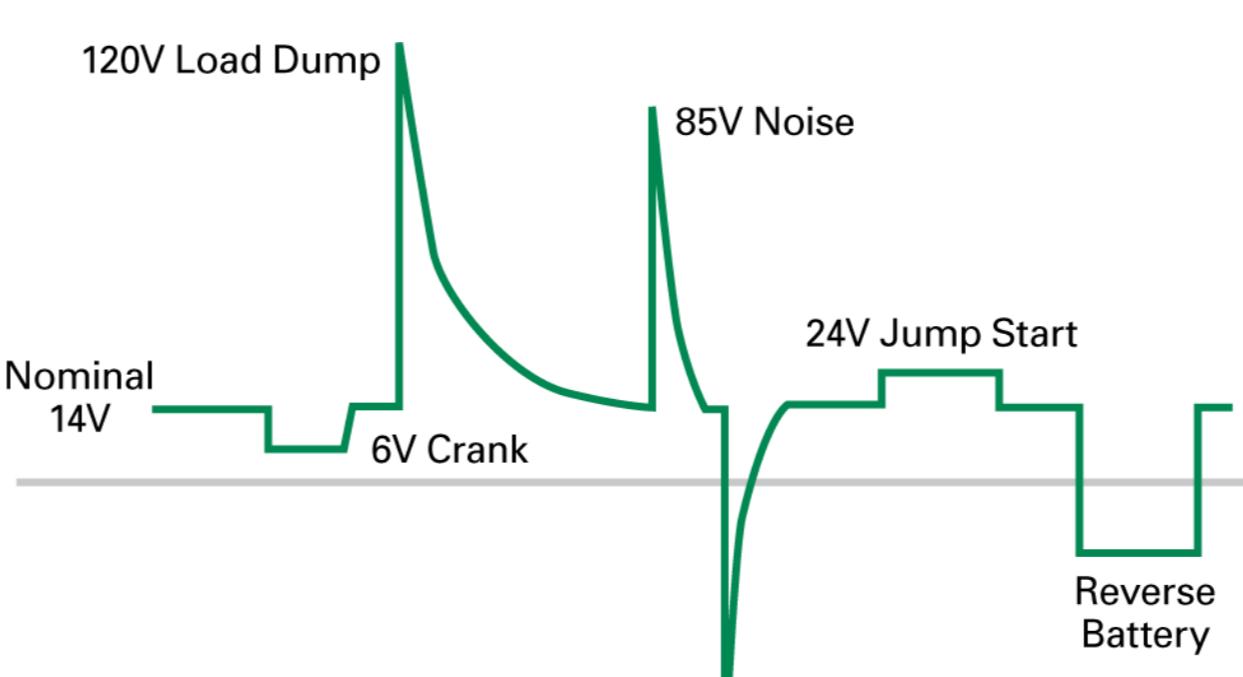
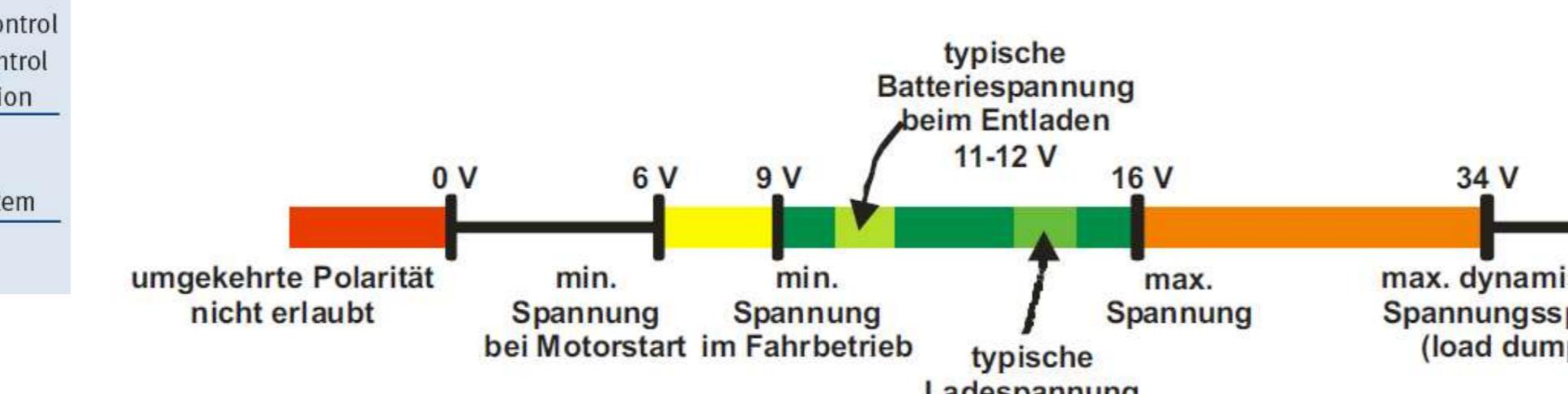
Body Applications



Automotive Applications

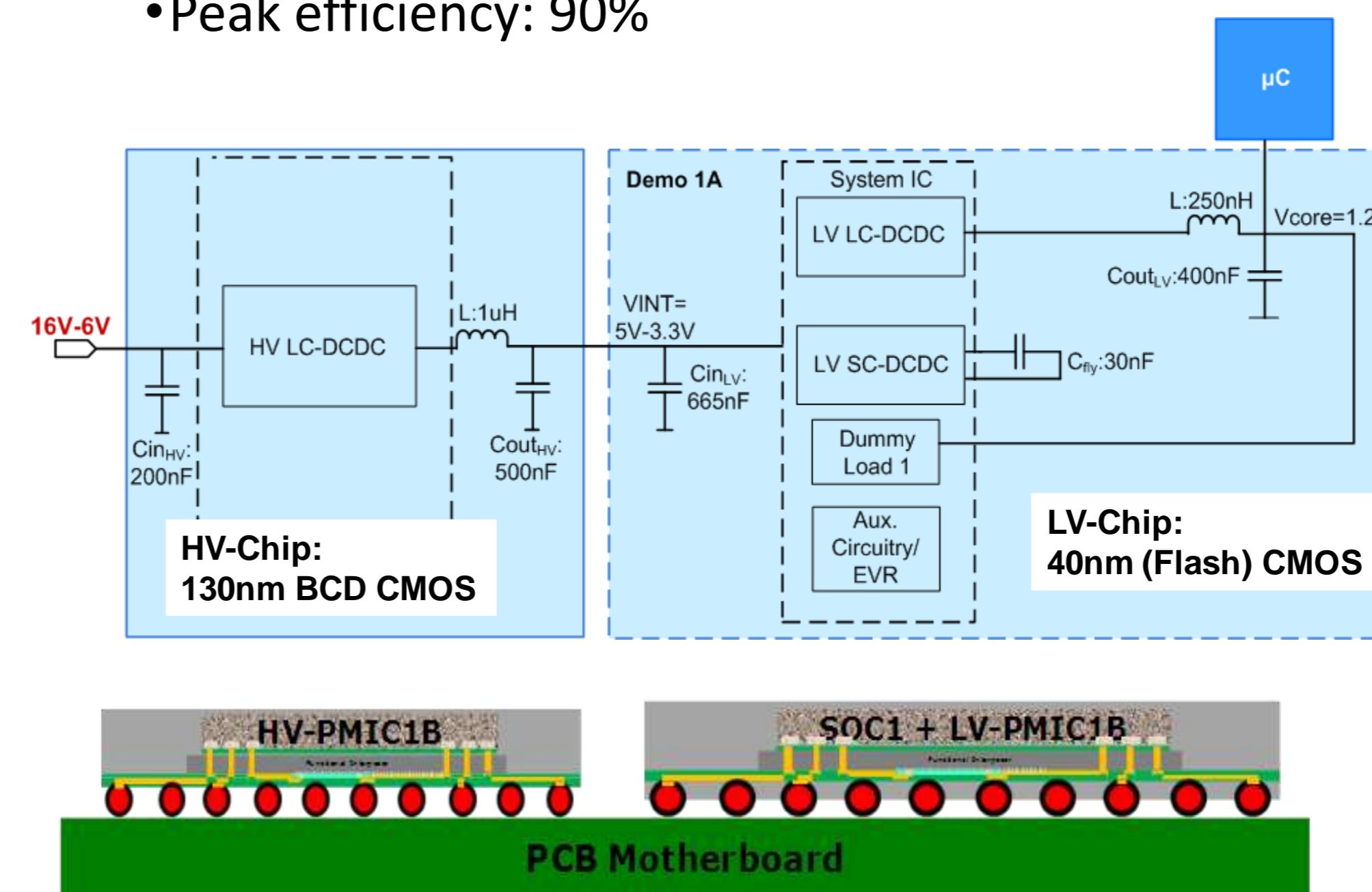


Board Supply in a Car

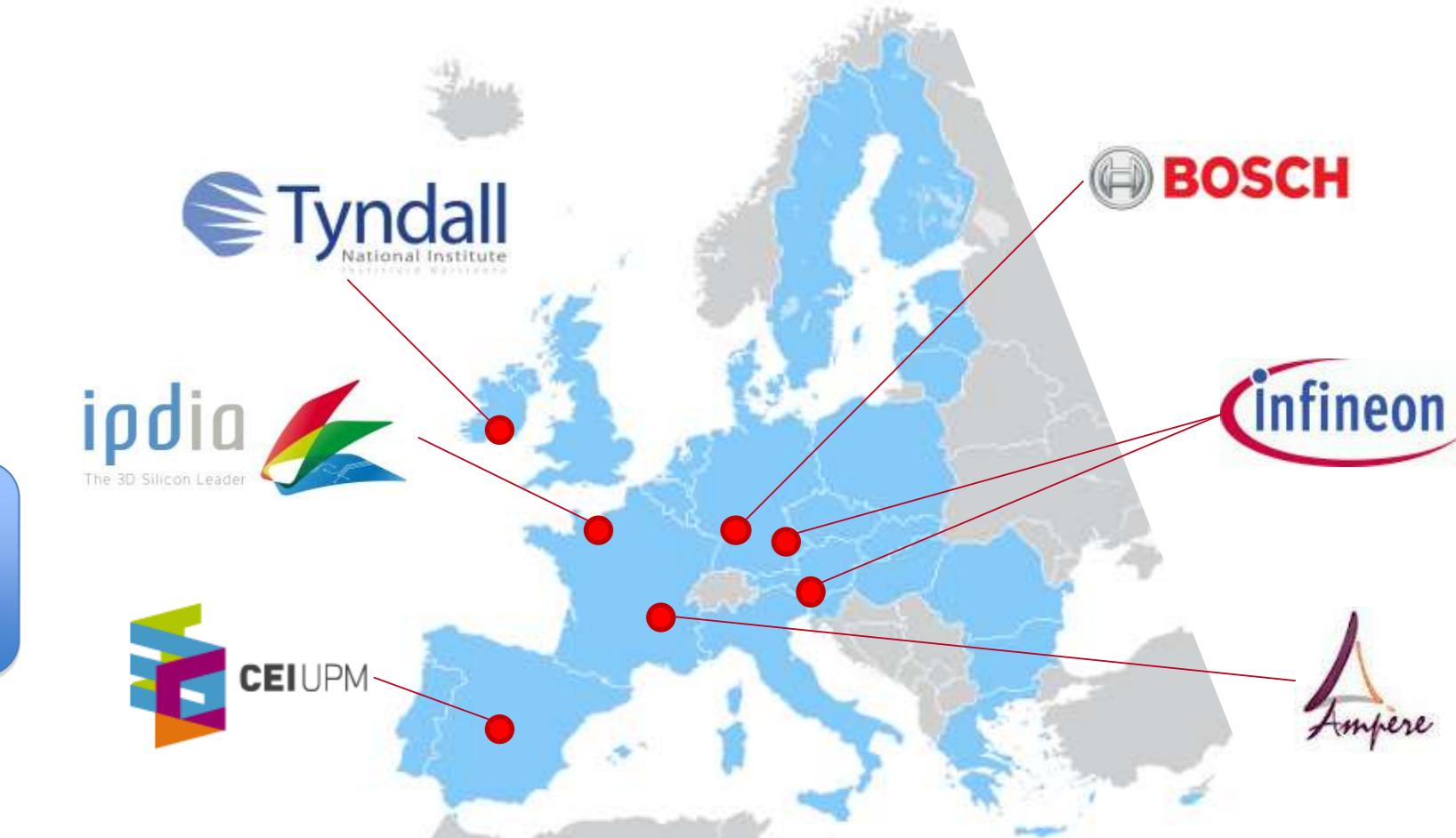


Demonstrator

- High Voltage Pre-Regulator:
 - Vin: 16V...6V
 - Vout: 5V/3.3V
 - Iload_{max}: 500mA
 - Peak efficiency: 80%
- Low Voltage Regulators
 - Vin: 5V/3.3V
 - Vout: 1.2V/1.3V
 - Iload_{max}: 500mA/200mA
 - Peak efficiency: 90%

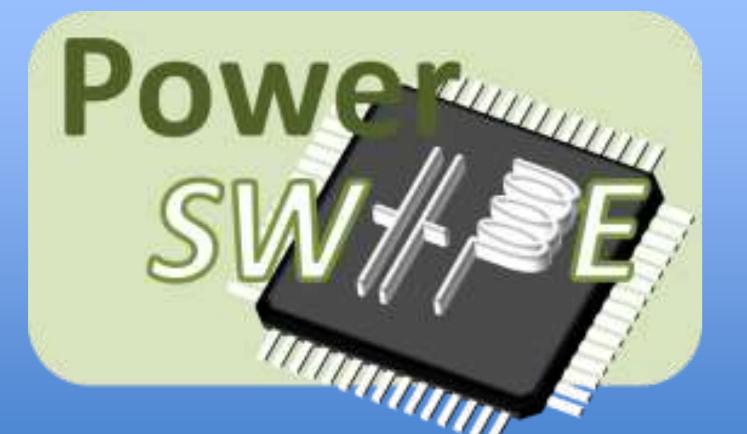


Project Partners



- IFAT: Chip Design
- Lyon: Chip Design
- IFAG: Packaging
- Tyndall: Power Inductor, Consortium Lead
- IPDiA: Capacitors & Interposer
- UPM: Concept
- Bosch: Application & Requirements

• Funded by EU FP7-ICT-2011-8 –
PowerSWIPE – Project no.: 318529



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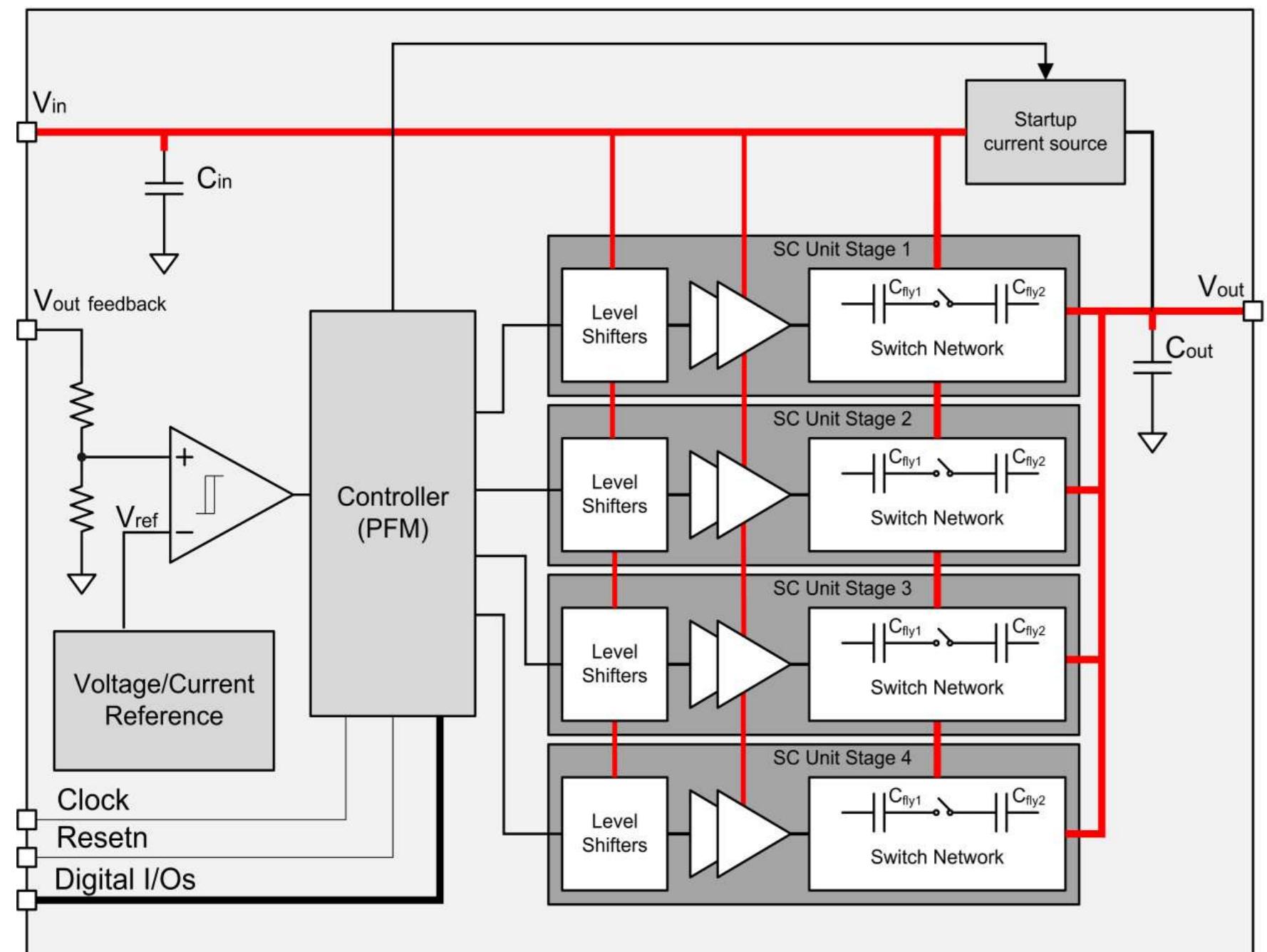
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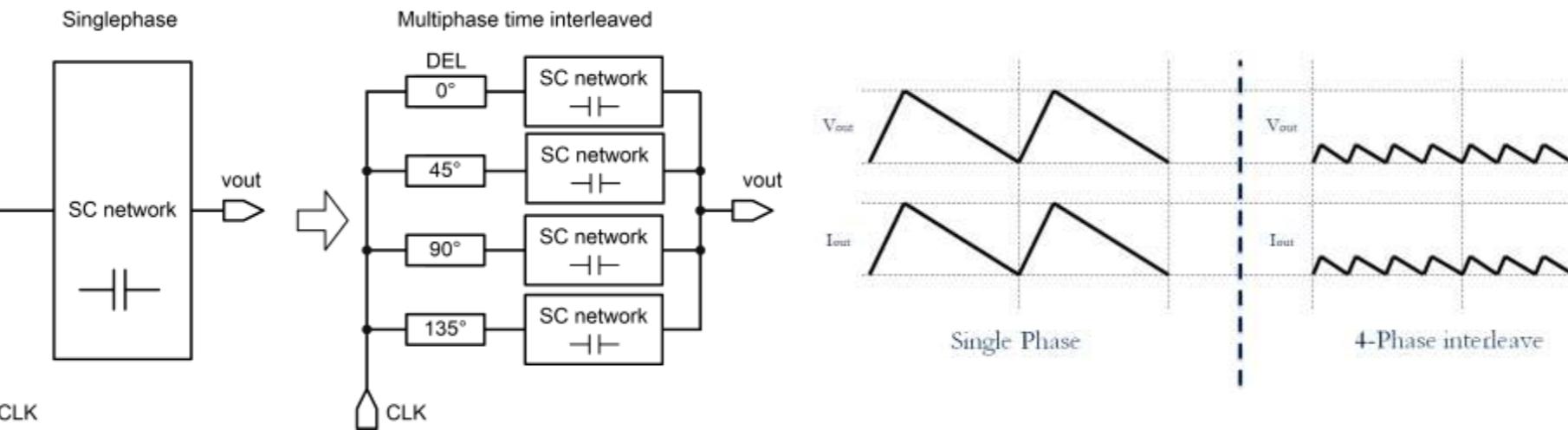
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SC DC-DC

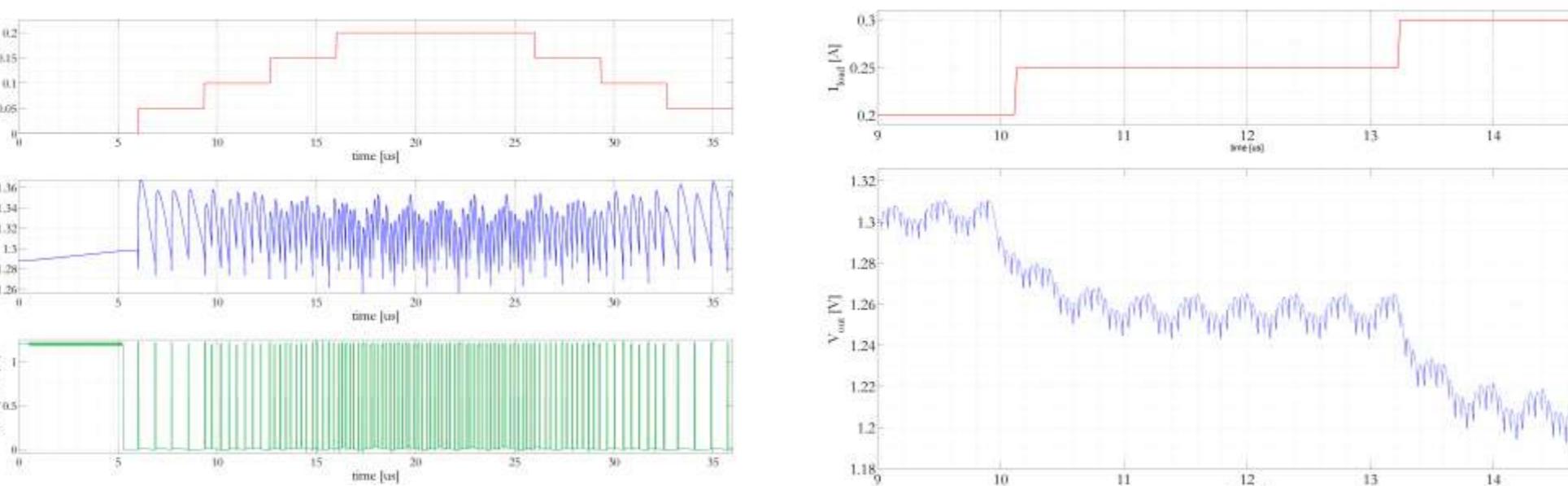


Multi Phase Topology



- Multi-phase
 - limits output voltage ripple
 - limits chip noise (lower current peaks at the input)

Simulation Results



- SC DC-DC Converter:
 - 40nm CMOS Technology
 - Series-Parallel
 - Cfly: 8x30nF
 - Cout: 260nF
 - Vout: 1.2V/1.3V

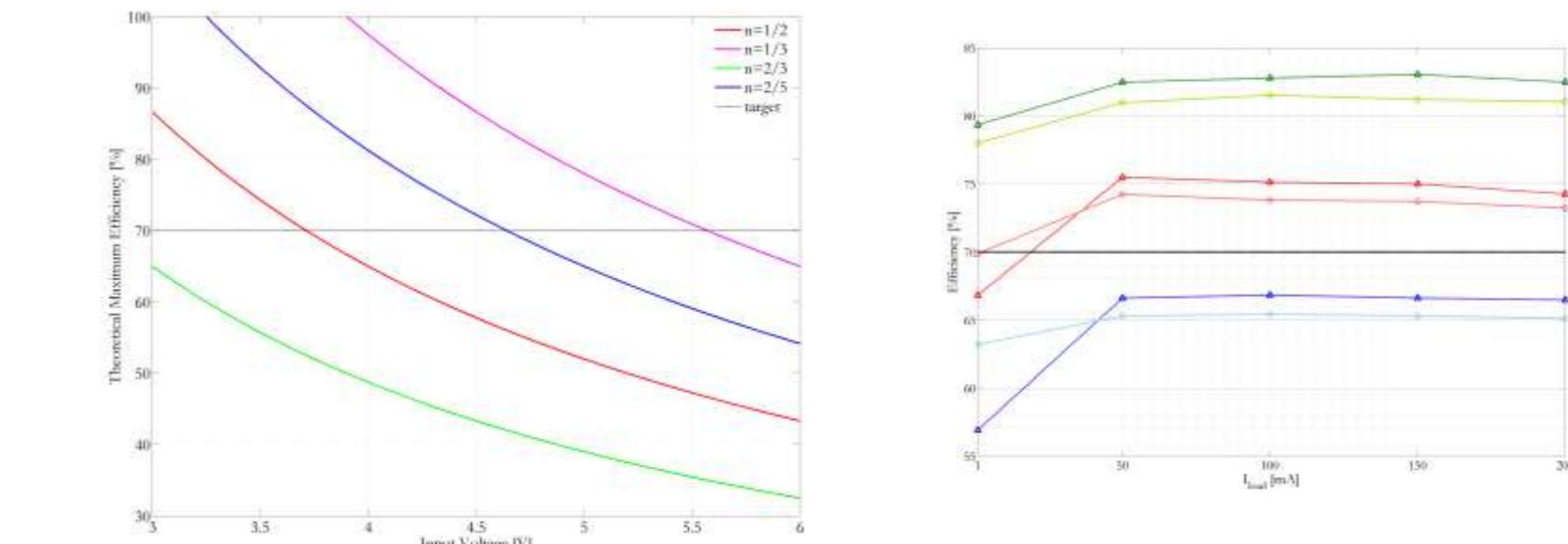
- Gain modes:
 - 1/2 (Vdd=3.3V)
 - 1/3 (Vdd=5V)

- 4 Interleaved Stages:
 - 2 Cfly/stage
 - 9 Switches/stage
 - fsw = 2.5 MHz

- Controller:
 - Pulse Frequency Modulation

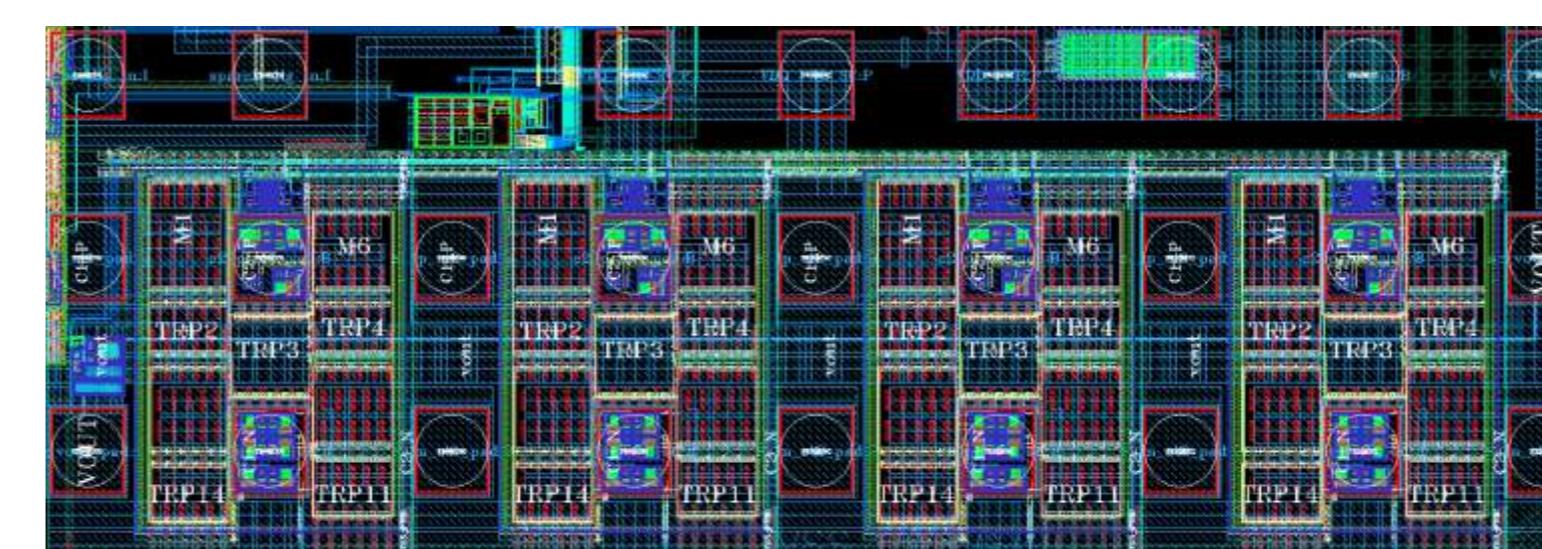
- Driving Capability under Worst Case Conditions (PVT)

Efficiency Simulations

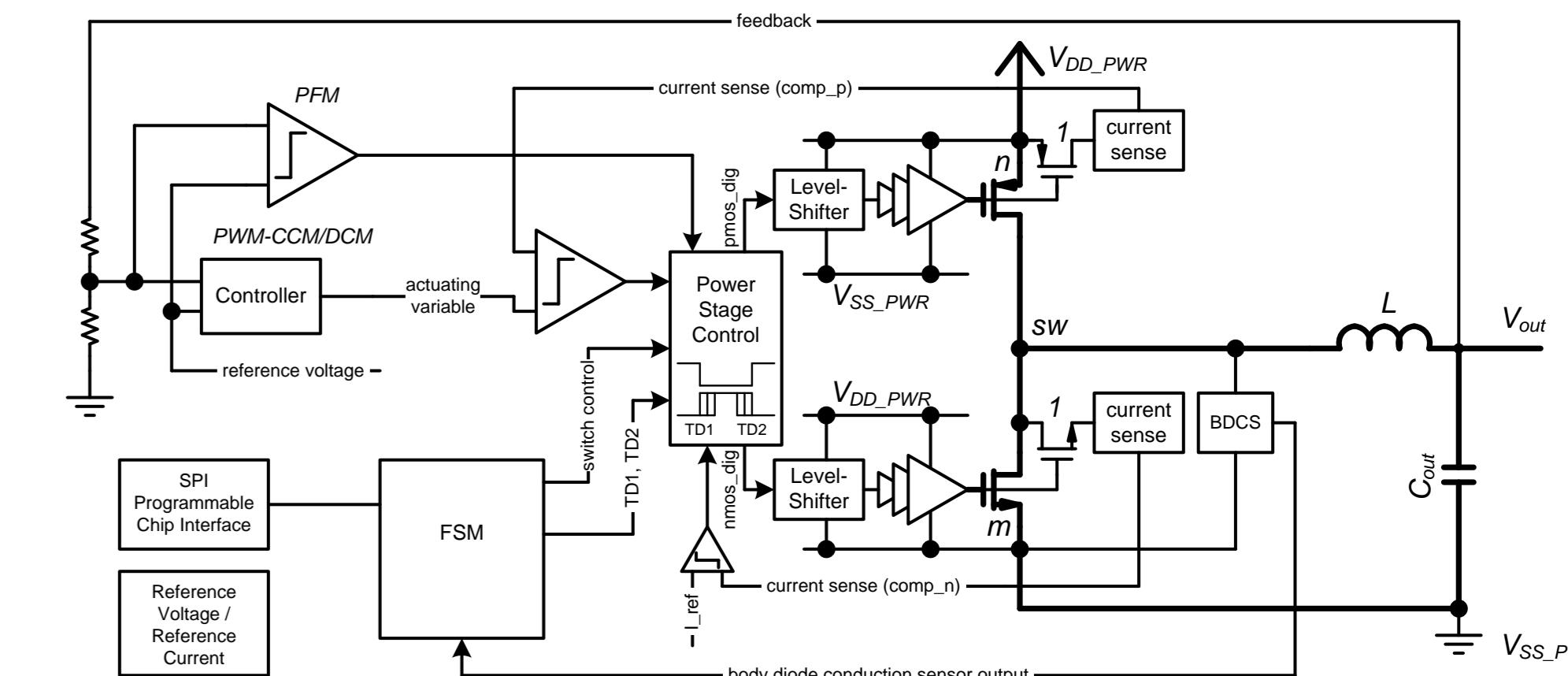


- Simulated Converter Efficiency for Different Input Voltages
- Peak Efficiency at $I_{load} = 100\text{mA}$: 84%
- Switching Activity: 20MHz

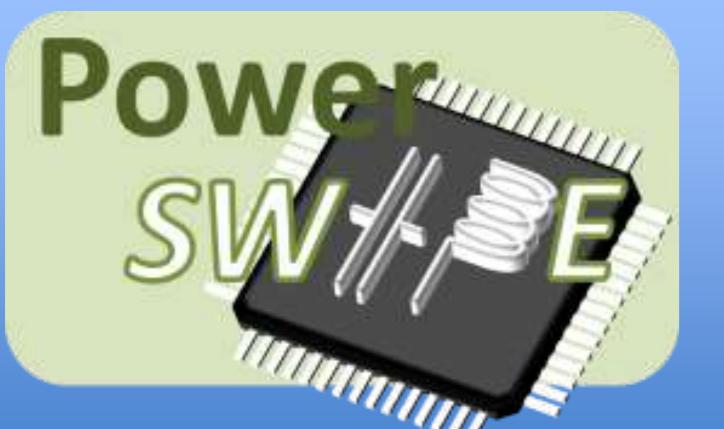
Layout SC DC-DC



LC DC-DC



- LC DC-DC Buck Converter:
 - 40nm CMOS Technology
 - Vin: 5V/3.3V
 - Vout: 1.2V/1.3V
 - $I_{load_{max}}$: 500mA
 - fsw: 10MHz
 - Peak efficiency: 90%
- Lout/Cout: 250nH/350nF
- High Side and Low Side Current Sensing
 - Peak Current Control
 - DCM Mode
 - Over Current Protection
- Automatic Dead Time Optimization in the Power Stage
- Operating Modes:
 - PWM-CCM, PWM-DCM, PFM



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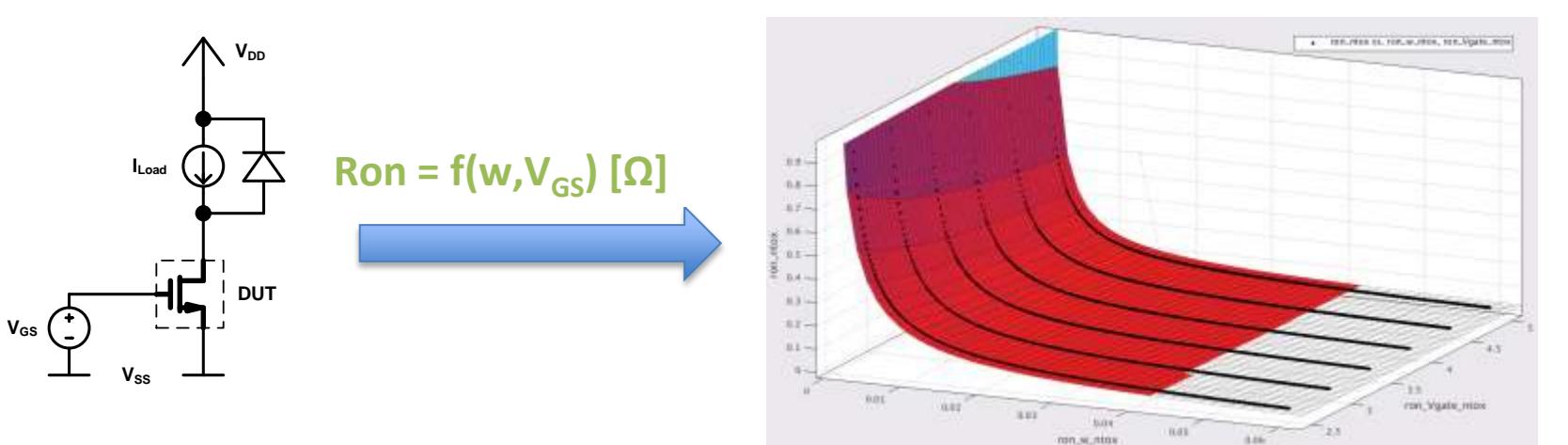
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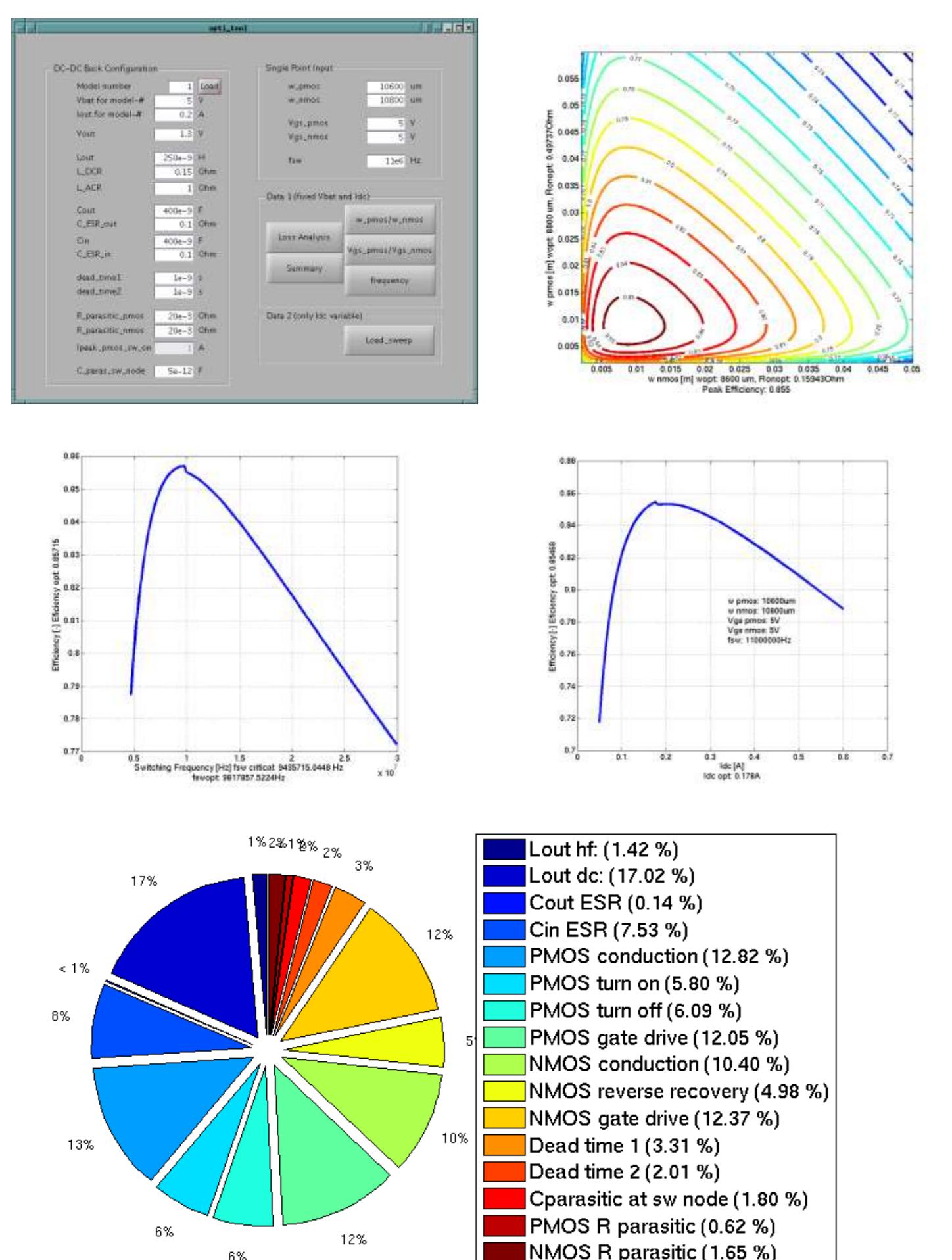


Power Stage Optimization

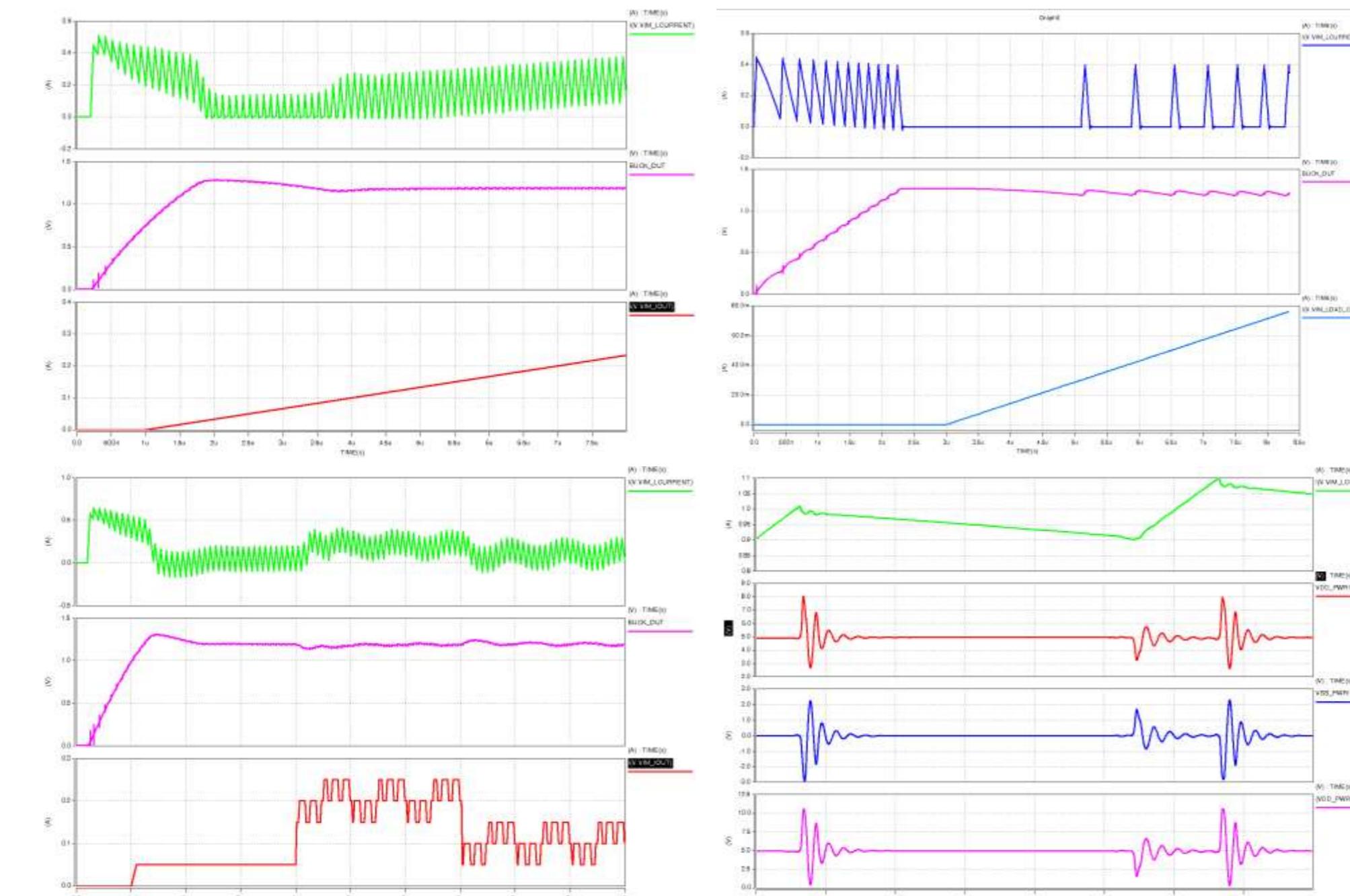
- Device Properties Extracted from Spice Simulations, Optimization is Done in Matlab
- Device Properties: Ron, Turn on Losses, Turn off Losses, Reverse Recovery Losses, Gate Drive Losses, Body Diode Conduction Forward Voltage
- Example Ron:



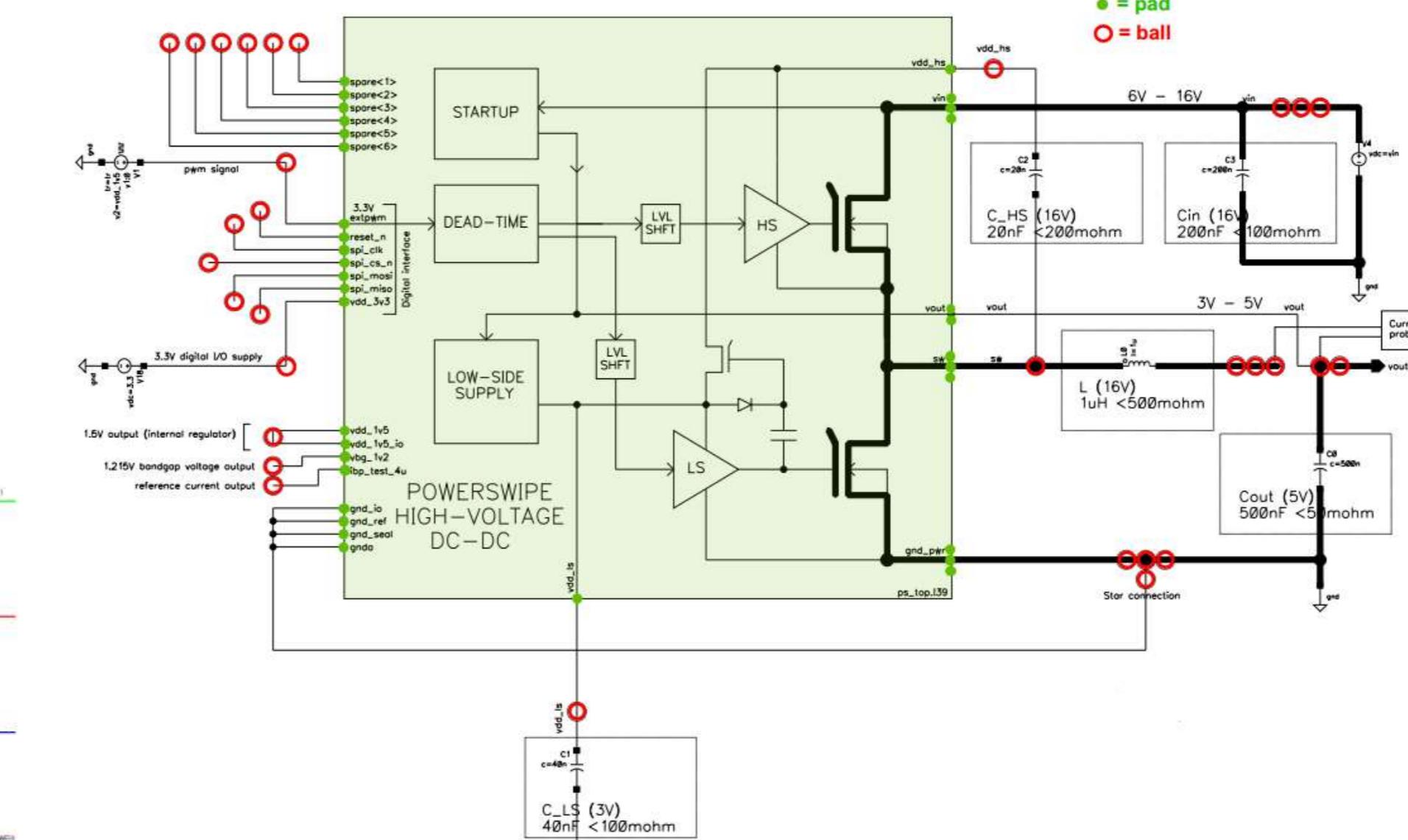
- Optimization Tool



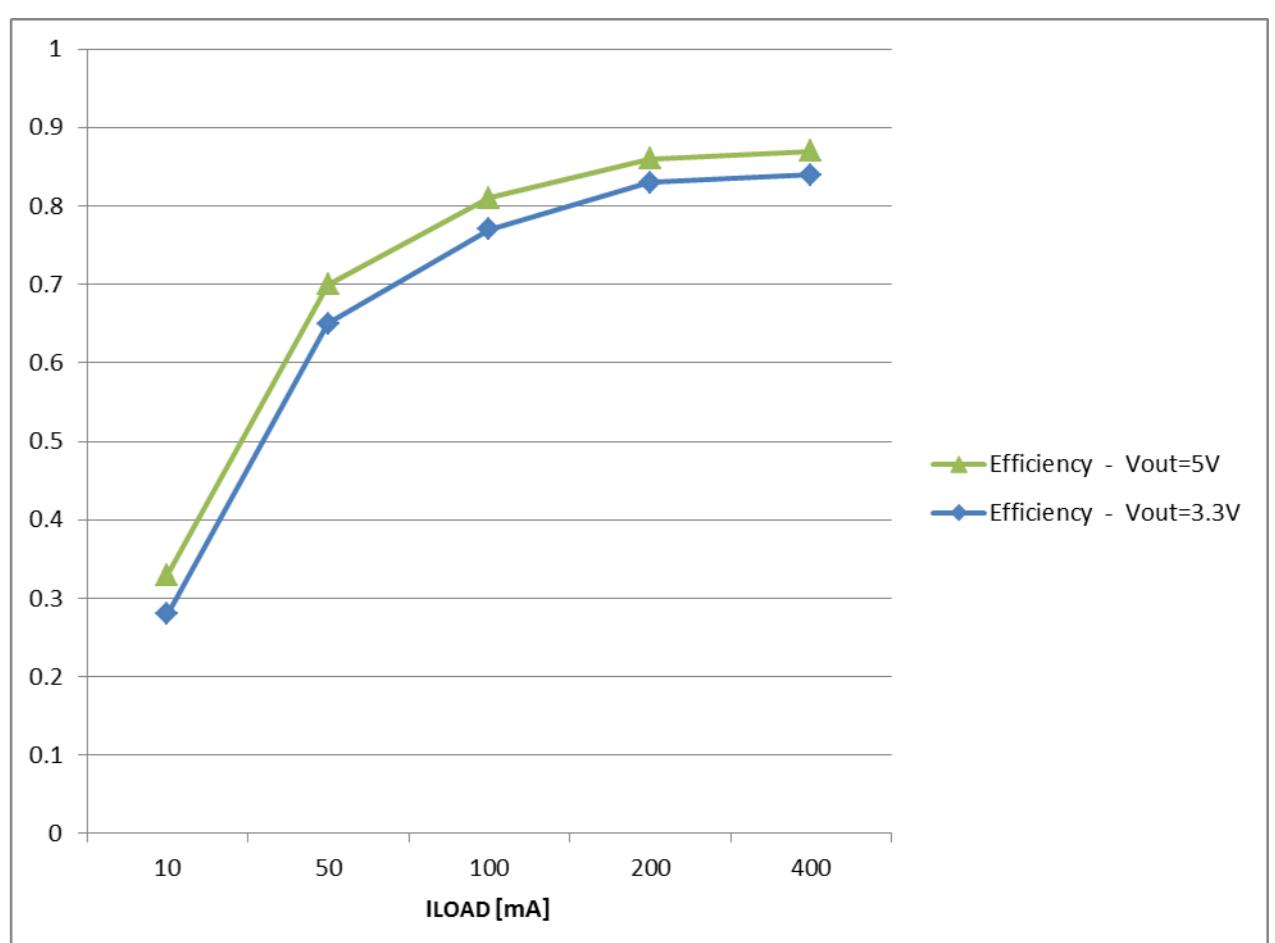
Simulation Results



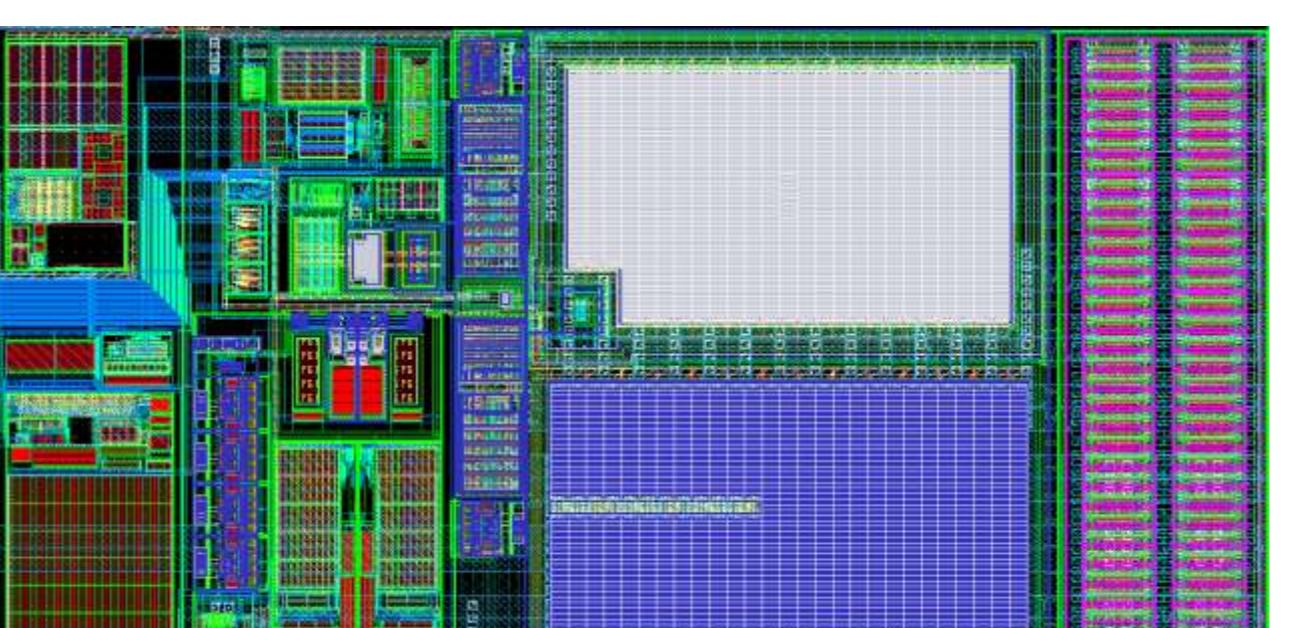
HV DC-DC



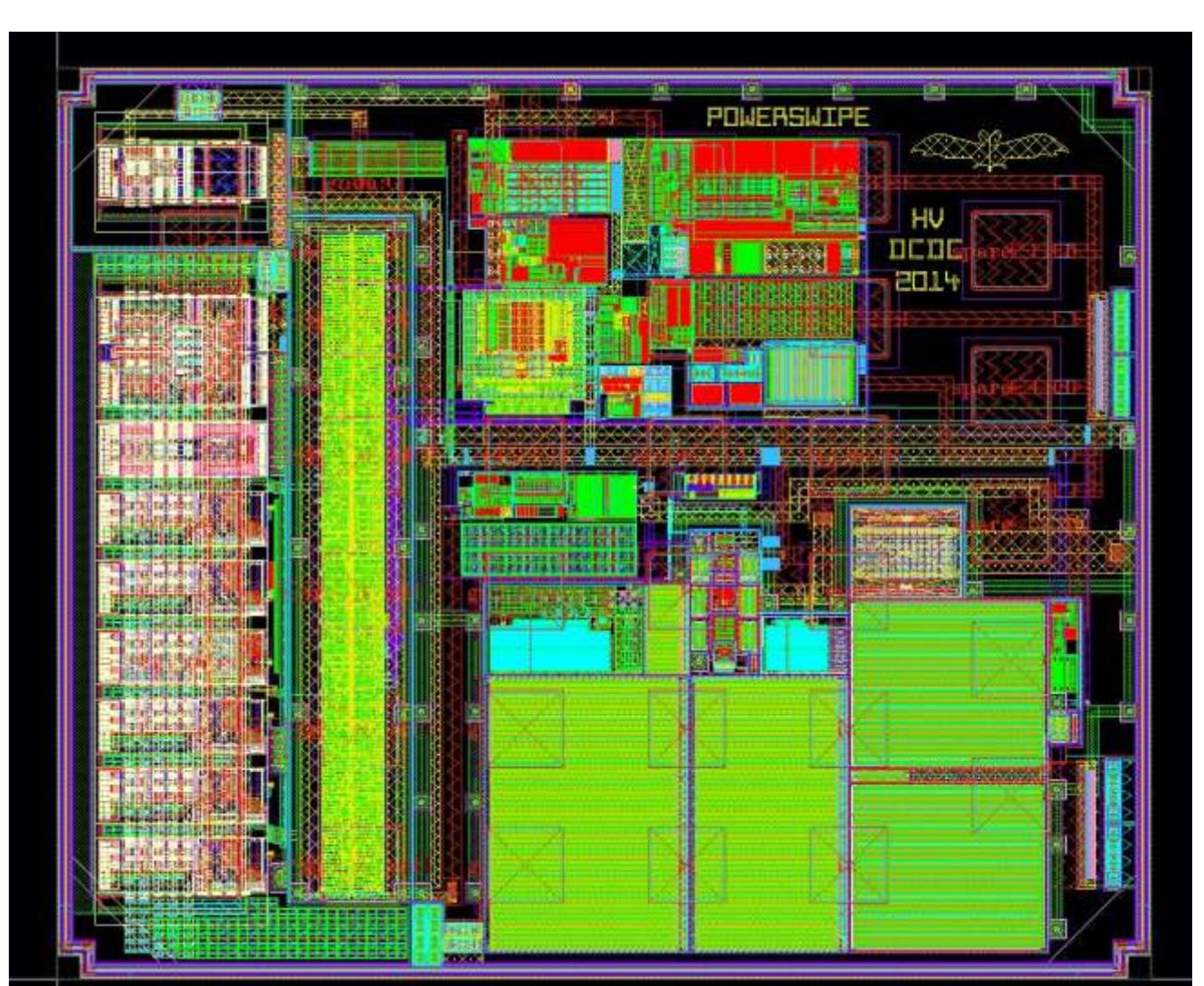
Simulation Results



Layout LV DC-DC



Layout HV DC-DC



- HV DC-DC Buck Converter:
 - 130nm BCD Technology
 - Vin: 6V up to 16V
 - Vout: 5V/3.3V
 - Iload_{max}: 500mA
 - fsw: 10MHz
 - Peak efficiency: 90%
- Lout/Cout: 1uH/1uF
- Cls = 40nF (capacitor for low-side driver supply)
- Chs = 20nF (bootstrap capacitor for high-side driver)
- Dead Time Optimization
- Operating Modes:
 - PWM-CCM